TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74ACT240P,TC74ACT240F,TC74ACT240FW,TC74ACT240FT TC74ACT244P,TC74ACT244F,TC74ACT244FW,TC74ACT244FT

Octal Bus Buffer

TC74ACT240P/F/FW/FT Inverted, 3-State

Outputs

TC74ACT244P/F/FW/FT Non-Inverted, 3-State Outputs

The TC74ACT240 and 244 are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The 74ACT240 is an inverting 3-state buffer while the 74ACT244 is non-inverting. Both devices have two active-low output enables.

These devices are designed to be used in such applications as 3-state memory address drivers.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

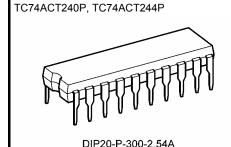
#### **Features**

- High speed:  $t_{pd} = 5.0 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$
- Low power dissipation: I<sub>CC</sub> = 8 μA (max) at Ta = 25°C
- Compatible with TTL outputs:  $V_{IL} = 0.8 \text{ V (max)}$   $V_{IH} = 2.0 \text{ V (min)}$
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 24$  mA (min) Capability of driving 50  $\Omega$

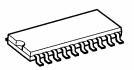
transmission lines.

- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Pin and function compatible with 74F240/244

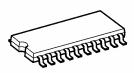
Note: xxxFW (JEDEC SOP) is not available in Japan.



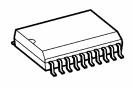
TC74ACT240F, TC74ACT244F



SOP20-P-300-1.27A



SOP20-P-300-1.27 TC74ACT240FW, TC74ACT244FW



SOL20-P-300-1.27 TC74ACT240FT, TC74ACT244FT

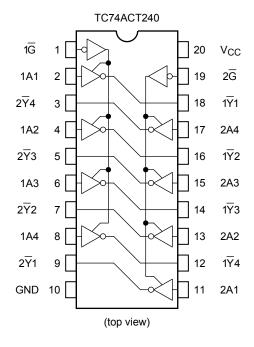


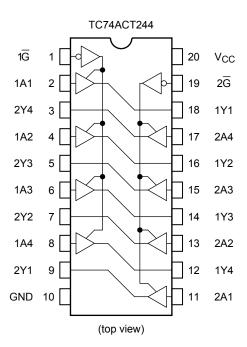
TSSOP20-P-0044-0.65A

Weight

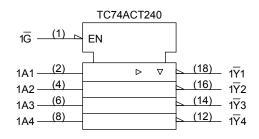
DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.) SOP20-P-300-1.27 : 0.22 g (typ.) SOL20-P-300-1.27 : 0.46 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.)

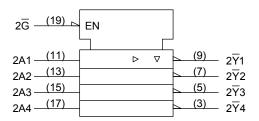
## **Pin Assignment**

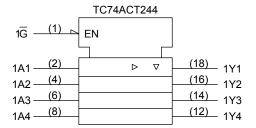


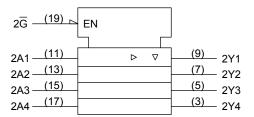


## **IEC Logic Symbol**









## **Truth Table**

Inputs		Outputs				
G	A <sub>n</sub>	Y <sub>n</sub> (244)	Ÿ <sub>n</sub> (240)			
L	L	L	Н			
L	Н	Н	L			
Н	Х	Z	Z			

X: Don't care

Z: High impedance



# **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	−0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	٧
Input diode current	I <sub>IK</sub>	±20	mA
Output diode current	lok	±50	mA
DC output current	lout	±50	mA
DC V <sub>CC</sub> /ground current	Icc	±200	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T <sub>stg</sub>	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

# **Recommended Operating Conditions (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	4.5 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	−40 to 85	°C
Input rise and fall time	dt/dV	0 to 10	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

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#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition V <sub>CC</sub> (V)			Ta = 25°C			Ta = −40 to 85°C		Unit	
Sharastonesis	Cymbol					Min	Тур.	Max	Min	Max	Onit
High-level input voltage	V <sub>IH</sub>	-			4.5 to 5.5	2.0			2.0	_	V
Low-level input voltage	V <sub>IL</sub>	_			4.5 to 5.5	-	_	0.8	_	0.8	٧
	V <sub>ОН</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA		4.5	4.4	4.5	_	4.4	_	
High-level output voltage			I <sub>OH</sub> = −24 mA		4.5	3.94	_	_	3.80	_	V
			I <sub>OH</sub> = -75 mA	(Note)	5.5	_	_	_	3.85	_	
	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA		4.5	_	0.0	0.1	_	0.1	
Low-level output voltage			I <sub>OL</sub> = 24 mA		4.5	_	_	0.36	_	0.44	V
Voltage			I <sub>OL</sub> = 75 mA	(Note)	5.5	_	_	_	_	1.65	
3-state output off-state current	l <sub>OZ</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = V_{CC}$ or GND			5.5	ı	_	±0.5	_	±5.0	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND			5.5	1	_	±0.1	_	±1.0	μΑ
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND			5.5	_	_	8.0	_	80.0	μΑ
	IC	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND			5.5	_	_	1.35	_	1.5	mA

Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

## AC Characteristics ( $C_L = 50 \text{ pF}$ , $R_L = 500 \Omega$ , input: $t_r = t_f = 3 \text{ ns}$ )

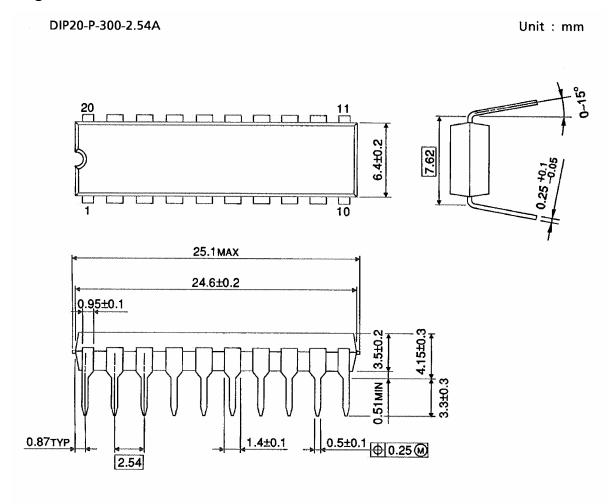
Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	,		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
Propagation delay	t <sub>pLH</sub>	_	5.0 ± 0.5	_	5.7	8.0	1.0	9.0	ns
time	t <sub>pHL</sub>		0.0 = 0.0		0.,	0.0	0	3.0	0
Output enable time	t <sub>pZL</sub>	_	5.0 ± 0.5	_	6.0	9.0	1.0	10.5	ns
Catpat chable time	t <sub>pZH</sub>								
Output disable time	t <sub>pLZ</sub>	_	5.0 ± 0.5	_	5.9	8.5	1.0	10.0	ns
Catpat dicable time	t <sub>pHZ</sub>								
Input capacitance	C <sub>IN</sub>	_		_	5	10	_	10	pF
Output capacitance	C <sub>OUT</sub>	_		_	10	1	_	_	pF
Power dissipation capacitance	C <sub>PD</sub>	TC74ACT240		_	25	_	_	_	pF
	(Note)	TC74ACT244		_	29	_	_	_	PΓ

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per bit)$ 

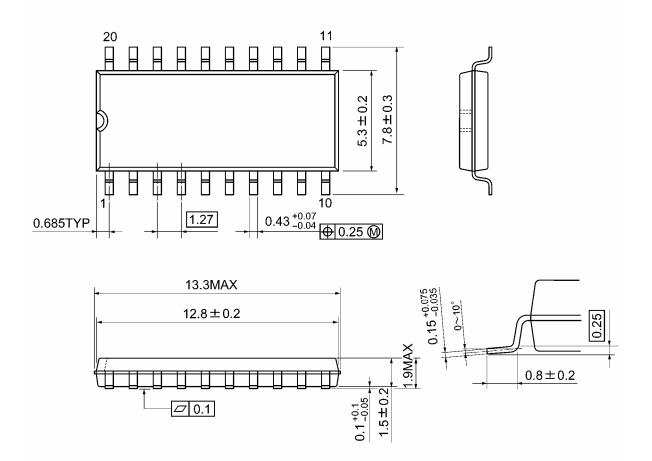




Weight: 1.30 g (typ.)



SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)



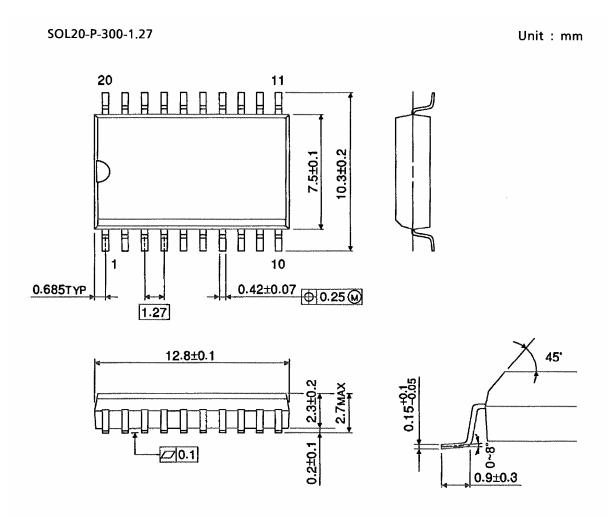
SOP20-P-300-1.27 Unit: mm 20 11  $5.3 \pm 0.2$ 7.8±0.3 (300mil) 7.62 B 10 0.43±0.1 0.25 M 0.685TYP 1.27 13.3MAX 12.8±0.2 **2**0.1 0.8±0.2

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Weight: 0.22 g (typ.)



# **Package Dimensions (Note)**



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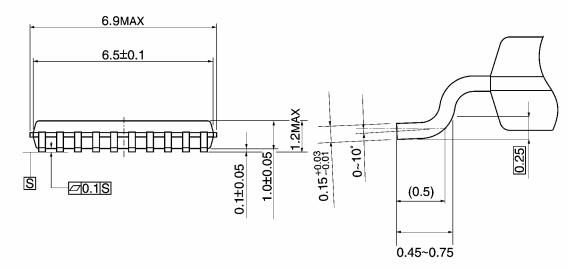
Note: This package is not available in Japan.

Weight: 0.46 g (typ.)



Unit: mm

20
11
10
0.325TYP
0.65
0.22-0.06
0.1300



Weight: 0.08 g (typ.)

Note: Lead (Pb)-Free Packages

DIP20-P-300-2.54A SOP20-P-300-1.27A TSSOP20-P-0044-0.65A

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